Static Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	75			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.085		V/°C	Reference to 25°C, I _D = 1mA
R _{DS(on)}	Static Drain-to-Source On-Resistance		3.6	4.5	mΩ	V _{GS} = 10V, I _D = 125A ④
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
gfs	Forward Transconductance	130			S	$V_{DS} = 25V, I_D = 125A^{\textcircled{4}}$
I _{DSS}	Drain-to-Source Leakage Current			20	μΑ	$V_{DS} = 75V, V_{GS} = 0V$
				250	1	$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 150^{\circ}C$
I _{GSS}	Gate-to-Source Forward Leakage			200	nA	V _{GS} = 20V
	Gate-to-Source Reverse Leakage			-200	1	V _{GS} = -20V

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
Q_g	Total Gate Charge		410	620		I _D = 125A
Q_{gs}	Gate-to-Source Charge		92	140	nC	$V_{DS} = 60V$
Q_{gd}	Gate-to-Drain ("Miller") Charge		140	210	1	V _{GS} = 10V ④
t _{d(on)}	Turn-On Delay Time		23			$V_{DD} = 38V$
t _r	Rise Time		190		1	I _D = 125A
t _{d(off)}	Turn-Off Delay Time		130		ns	$R_G = 1.2\Omega$
t _f	Fall Time		130		1	V _{GS} = 10V ④
L _D	Internal Drain Inductance		5.0			Between lead,
					nH	6mm (0.25in.)
L _S	Internal Source Inductance		13			from package
						and center of die contact
C _{iss}	Input Capacitance		13000			$V_{GS} = 0V$
Coss	Output Capacitance		2100		pF	$V_{DS} = 25V$
C _{rss}	Reverse Transfer Capacitance		500		1	f = 1.0MHz, See Fig. 5
Coss	Output Capacitance		9780		[$V_{GS} = 0V, V_{DS} = 1.0V, f = 1.0MHz$
Coss	Output Capacitance		1360		1	$V_{GS} = 0V, V_{DS} = 60V, f = 1.0MHz$
C _{oss} eff.	Effective Output Capacitance (5)		2320		1	$V_{GS} = 0V$, $V_{DS} = 0V$ to $60V$

Diode Characteristics

	Parameter	Min.	Тур.	Max.	Units	Conditions
I _S	Continuous Source Current			2096		MOSFET symbol
	(Body Diode)				Α	showing the
I _{SM}	Pulsed Source Current		_	840		integral reverse
	(Body Diode) ①					p-n junction diode.
V_{SD}	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C$, $I_S = 125A$, $V_{GS} = 0V$ ④
t _{rr}	Reverse Recovery Time		140	210	ns	$T_J = 25^{\circ}C, I_F = 125A$
Q _{rr}	Reverse Recovery Charge		880	1320	nC	di/dt = 100A/μs ④
t _{on}	Forward Turn-On Time	Intrinsio	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)			

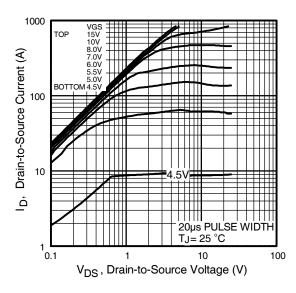
Notes:

- Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11).
- $\label{eq:tau} \begin{tabular}{ll} \hline \& Starting $T_J=25^\circ$C, $L=0.25mH$\\ $R_G=25\Omega, I_{AS}=125A.$ (See Figure 12). \\ \hline \end{tabular}$
- ③ I_{SD} \leq 125A, di/dt \leq 260A/ μ s, V_{DD} \leq V_{(BR)DSS}, T_J \leq 175°C.
- 4 Pulse width \leq 400 μ s; duty cycle \leq 2%.
- $^{\circ}$ C_{oss} eff. is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 to 80% V_{DSS} .
- © Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 90A.
- ② Limited by T_{Jmax}, see Fig.12a, 12b, 15, 16 for typical repetitive avalanche performance.
- $\ \, \mathbb{8} \, \, \, \text{R}_{\theta} \,$ is measured at T_{J} of approximately 90°C.

Qualification Information[†]

		Automotive				
		(per AEC-Q101) ^{††}				
Qualification Level		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.				
Moisture Sensitivity Level		TO-247	MSL1			
	Machine Model	Class M4 (+/- 425V) ***				
		AEC-Q101-002				
FOR	Human Body Model	Class H3A (+/- 8000V) †††				
ESD		AEC-Q101-001				
	Charged Device	Class C5 (+/- 1125V) †††				
	Model		AEC-Q101-005			
RoHS Compliant		Yes				

- † Qualification standards can be found at International Rectifier's web site: http://www.irf.com/
- †† Exceptions to AEC-Q101 requirements are noted in the qualification report.
- ††† Highest passing voltage.



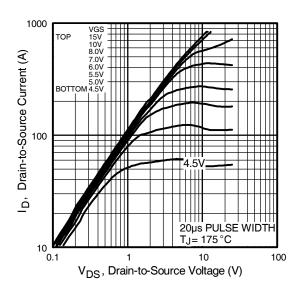
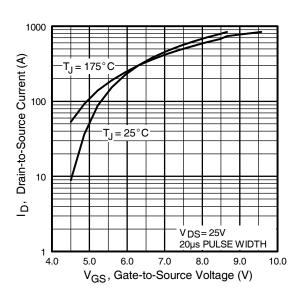


Fig 1. Typical Output Characteristics

Fig 2. Typical Output Characteristics



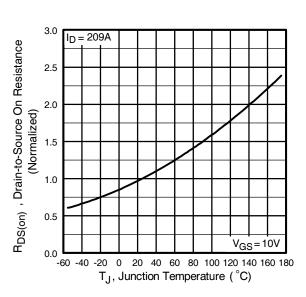
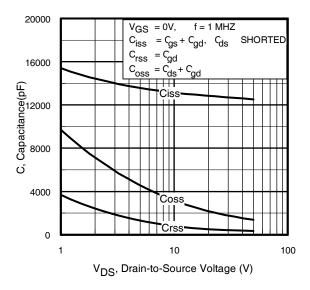


Fig 3. Typical Transfer Characteristics

Fig 4. Normalized On-Resistance Vs. Temperature



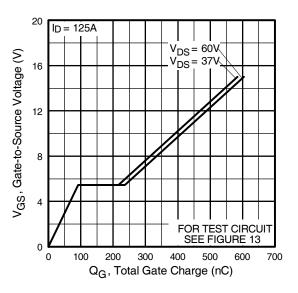
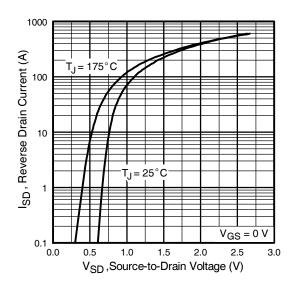


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage



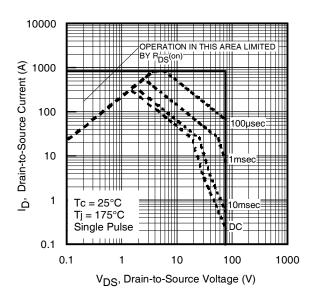


Fig 7. Typical Source-Drain Diode Forward Voltage

Fig 8. Maximum Safe Operating Area

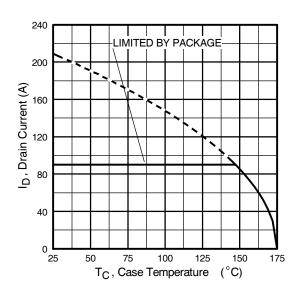


Fig 9. Maximum Drain Current Vs. Case Temperature

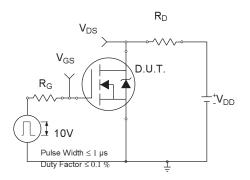


Fig 10a. Switching Time Test Circuit

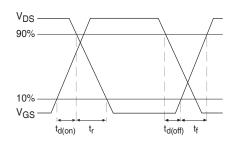


Fig 10b. Switching Time Waveforms

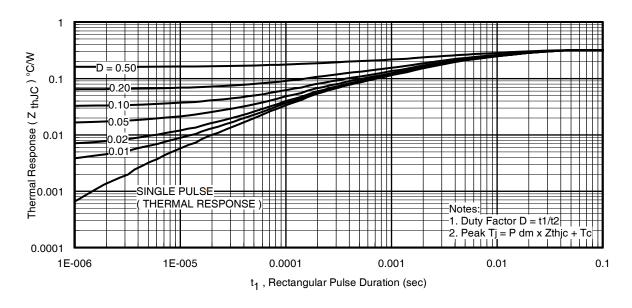


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case

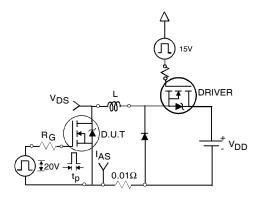


Fig 12a. Unclamped Inductive Test Circuit

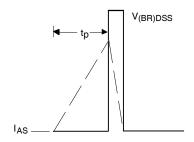


Fig 12b. Unclamped Inductive Waveforms

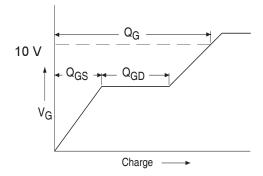


Fig 13a. Basic Gate Charge Waveform

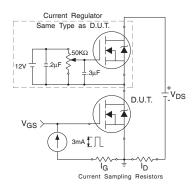


Fig 13b. Gate Charge Test Circuit www.irf.com

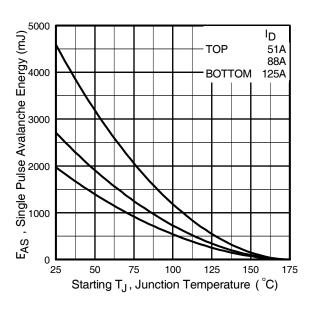


Fig 12c. Maximum Avalanche Energy Vs. Drain Current

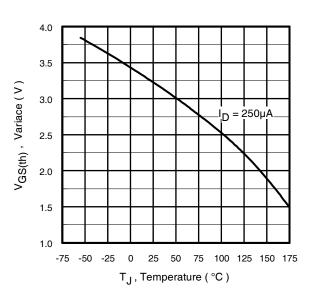


Fig 14. Threshold Voltage Vs. Temperature

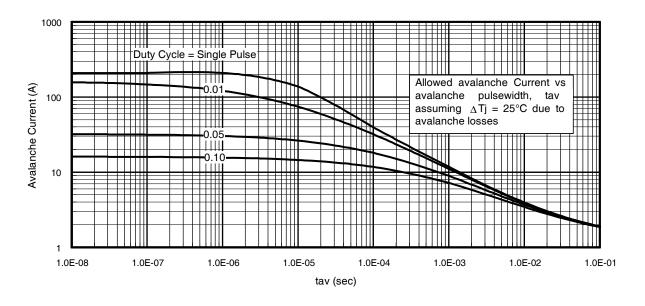
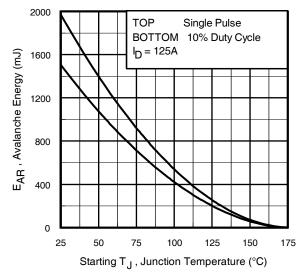


Fig 15. Typical Avalanche Current Vs. Pulsewidth



Notes on Repetitive Avalanche Curves, Figures 15, 16: (For further info, see AN-1005 at www.irf.com)

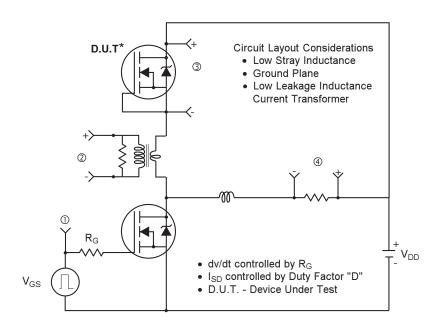
- Avalanche failures assumption:
 Purely a thermal phenomenon and failure occurs at a
 - temperature far in excess of T_{jmax}. This is validated for every part type.
- 2. Safe operation in Avalanche is allowed as long $\mbox{asT}_{\mbox{\scriptsize jmax}}$ is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- 4. P_{D (ave)} = Average power dissipation per single avalanche pulse.
- BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. I_{av} = Allowable avalanche current.
- 7. ΔT = Allowable rise in junction temperature, not to exceed T_{jmax} (assumed as 25°C in Figure 15, 16).
 - t_{av} = Average time in avalanche.
 - D = Duty cycle in avalanche = $t_{av} \cdot f$

 $Z_{thJC}(D, t_{av})$ = Transient thermal resistance, see figure 11)

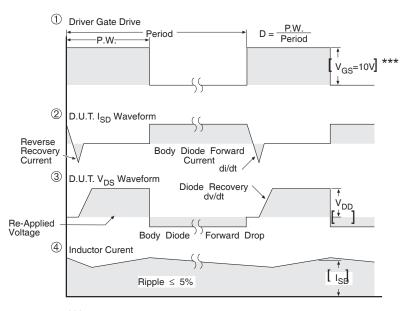
$$\begin{split} P_{D~(ave)} &= 1/2~(~1.3 \cdot BV \cdot I_{aV}) = \triangle T/~Z_{thJC} \\ I_{av} &= 2\triangle T/~[1.3 \cdot BV \cdot Z_{th}] \\ E_{AS~(AR)} &= P_{D~(ave)} \cdot t_{av} \end{split}$$

Fig 16. Maximum Avalanche Energy Vs. Temperature

Peak Diode Recovery dv/dt Test Circuit



^{*} Reverse Polarity of D.U.T for P-Channel

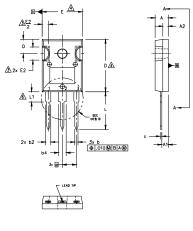


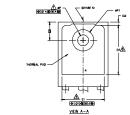
*** V_{GS} = 5.0V for Logic Level and 3V Drive Devices

Fig 17. For N-channel HEXFET® power MOSFETs

TO-247AC Package Outline

Dimensions are shown in millimeters (inches)









DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M 1994.

DIMENSIONS ARE SHOWN IN INCHES.

CONTOUR OF SLOT OPTIONAL.

DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.

THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS D1 & E1.

LEAD FINISH UNCONTROLLED IN L1.

 $\ensuremath{\mathrm{\mathsf{WP}}}$ TO HAVE A MAXIMUM DRAFT ANGLE OF 1.5 $^{\circ}$ TO THE TOP OF THE PART WITH A MAXIMUM HOLE DIAMETER OF .154 INCH.

OUTLINE CONFORMS TO JEDEC OUTLINE TO-247AC ,

SYMBOL	SYMBOL INCHES		MILLIM		
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	.183	.209	4.65	5.31	
A1	.087	.102	2.21	2.59	
A2	.059	.098	1,50	2.49	
ь	.039	.055	0.99	1.40	
ь1	.039	.053	0.99	1.35	
b2	.065	.094	1,65	2.39	
b3	.065	.092	1,65	2.34	
b4	.102	.135	2,59	3,43	
b5	.102	.133	2.59	3.38	
С	.015	.035	0.38	0.89	
c1	.015	.033	0.38	0.84	
D	.776	.815	19.71	20.70	4
D1	.515	-	13.08	-	5
D2	.020	.053	0.51	1.35	
Ε	.602	.625	15.29	15.87	4
E1	.530	-	13,46	-	
E2	.178	.216	4.52	5.49	
e	.215	BSC	5.46	5.46 BSC	
Øk	.010		0.25		
L	.559	.634	14.20	16.10	
L1	.146	.169	3,71	4.29	
ØΡ	.140	.144	3,56	3,66	
øP1	-	.291	-	7,39	
Q	.209	.224	5.31	5.69	
S	.217 BSC		5.51 BSC		

LEAD ASSIGNMENTS

HEXFET

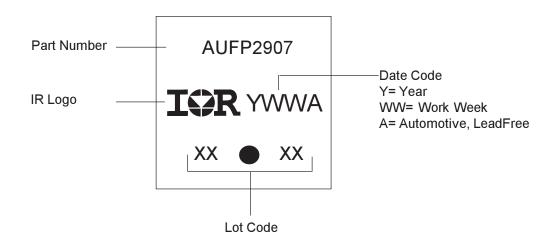
- 1.- GATE
- 2.- DRAIN 3.- SOURCE 4.- DRAIN

IGBTs, CoPACK

- 1.- GATE
 2.- COLLECTOR
 3.- EMITTER
 4.- COLLECTOR

- 1.- ANODE/OPEN 2.- CATHODE 3.- ANODE

TO-247AC Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

International
TOR Rectifier

AUIRFP2907

Ordering Information

Base part number	Package Type	Standard Pack		Complete Part Number
		Form	Quantity	
AUIRFP2907	TO-247	Tube	25	AUIRFP2907

AUIRFP2907

International

TOR Rectifier

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